

32nd International Workshop on Oxide Electronics (iWOE32)

Poster Session A (Sessions 1, 2, 3, 7, 8)

Date & Time: September 28, 2026 (Mon) 14:00 - 16:00 | Venue: Main Hall / Poster Area

Poster ID	Presenter & Affiliation	Abstract Title
PA-01	Muntaser Naamneh (Ben-Gurion Univ. of the Negev)	Universal Four-Fold Symmetry in Infinite-Layer Nickelates: From the Insulating Parent to the Superconducting State
PA-02	Youngdo Kim (Yale Univ.)	Polarization-Dependent EXAFS Analysis of Infinite-Layer Nickelate $\text{Nd}_{1-x}\text{Eu}_x\text{NiO}_2$
PA-03	Hideyuki Kawasoko (Tokyo Metropolitan Univ.)	Epitaxial Growth and Electronic Properties of Layered Nickelate $\text{Sr}_{2.5}\text{Bi}_{0.5}\text{NiO}_5$
PA-04	Rahaf Yaseen (Max Planck Institute for Solid State Research)	Superconductivity in As-Grown Bilayer Nickelate Thin Films
PA-05	Antoine Devinenti (Northwestern Univ.)	Evolution in Ruddlesden-Popper nickelate via soft-chemistry
PA-06	Lee Ki Hyuk (Chung-Ang Univ.)	Epitaxial Growth of La-Site-Substituted Bilayer Nickelate Thin Films and Emergent In-Plane Octahedral Rotation
PA-07	Haobo Li (The Univ. of Osaka)	Synthesis and investigation of Eu_2NiO_4 in Ruddlesden-Popper structure
PA-08	Kenta Natsui (Tokyo metropolitan Univ.)	Metallic Conduction in $\text{Sr}_{2.5}\text{Bi}_{0.5}\text{NiO}_5$ Epitaxial Thin Films by Controlling Growth Condition
PA-09	Seitaro Inoue (Tohoku Univ.)	Thickness Dependence of Electronic Structure and V-V Dimerization in VO_2 (110)R Ultrathin Films
PA-10	Masahito Sakoda (Hokkaido Univ.)	Thickness-Periodic Mott Insulators in CaRuO_3 Ultrathin Films: An Extraordinary Size Effect in Correlated Oxides
PA-11	Yusaku Hamada (Hokkaido Univ.)	Carrier-Doping-Induced Metal to Insulator Crossover in CaRuO_3 Thin Films
PA-12	Aniket Bajaj (Indian Institute of Science Education and Research Kolkata)	Thermal Runaway Instability Drives Electric Field Induced Breakdown of a Mott Insulator
PA-13	Josei Fujiwara (Science Tokyo)	Solid-phase synthesis of Cr-doped V_2O_3 thin films on $\alpha\text{-Al}_2\text{O}_3$ (01-12) substrates exhibiting metal-insulator transition at room-temperature
PA-14	Yuto Takatsu (Univ. of Tsukuba)	Theoretical Study of SVILC Qubits in Bi-2212 Cuprate Thin Films

PA-15	Yongjin Shin (Dankook Univ.)	Revealing the temperature-dependent phase transitions of LaTaO ₄ in Carpy-Galy structure
PA-16	Sandra Glotzer (Caltech)	Magnetic Field Induced Superconductivity in NbO
PA-17	Linshen Xing (Tohoku Univ.)	Anion-Gradient Engineering of Superconductivity in NbO-Based Oxynitride Epitaxial Thin Films
PA-18	Shu Takashima (Science Tokyo)	Repeated temperature modulation epitaxy of superconducting LiTi ₂ O ₄
PA-19	Michael Sing (Univ. of Würzburg)	Waterfall-like Incoherent States and Electron–Plasmon Coupling in Compressively Strained SrNbO ₃ Thin Films
PA-20	Andrés Santander-syro (Université Paris-Saclay)	Imaging the itinerant-to-localized transmutation of electrons across the metal-to-insulator transition
PA-21	Takuya Takashiro (Tohoku Univ.)	Direct Observation of Double Dirac-Cone Crossings and Strain-Enhanced Nontrivial Band Gap in a Topological Crystalline Insulator Thin Film
PA-22	Ryu Yukawa (Tohoku Univ.)	Carrier-density-driven evolution of two-dimensional electron systems on β -Ga ₂ O ₃ surface
PA-23	Suryo Putro (Tohoku Univ.)	Microscopic Origin of Photoinduced Two-Dimensional Electron System Formation at β -Ga ₂ O ₃ Surface
PA-24	Miho Kitamura (NanoTerasu Center, QST)	Current status of NanoTerasu BL ₀₆ U: beamline for micro- and nano-ARPES measurements
PA-25	Sim Hanjun (Sungkyunkwan Univ.)	Growth condition optimization for various chromium-oxide films by using an in- situ MBE-ARPES system
PA-26	Ronny Sutarto (Canadian Light Source)	Resonant soft x-ray scattering on layered nickelates and oxide interface
PA-27	Hayato Konaka (Tohoku Univ.)	in situ Synchrotron-Radiation Photoemission Spectroscopy of NbO ₂ Ultrathin Films
PA-28	Jasnamol Palakkal (Univ. of Göttingen)	The Oxidation Behavior of Nb oxides seen by X-ray Photoemission Spectroscopy
PA-29	Jessica Freese (Univ. of Saskatchewan)	Exploring surface electronic structure in titanates by in situ synchrotron resonant x-ray reflectometry
PA-30	Deok-yong Cho (Jeonbuk National Univ.)	Depth Profiling of Electron States at Buried Interface
PA-31	Mariana Palos (Imperial College London)	Scan, Shift, Lock: Switching and Control of Ferroic Domain Walls via STEM Probe Trajectories
PA-32	Ziqiao Wang (GBA Quantum Sci. Ctr.)	Shubnikov-de Haas Oscillations Reaching the Quantum Limit in Two-Dimensional Electron Systems at SrTiO ₃ (111) Interfaces

PA-33	Kenta Nakanishi (The Univ. of Osaka)	Lowest Proton Diffusion Barrier in EuNiO ₃ Revealed by DFT and EIS
PA-34	Merit Spring (Univ. of Würzburg)	In-situ Strain Engineering of Complex Oxide Membranes
PA-35	Giulia Meucci (Technical Univ. of Denmark)	Quantum dots in Freestanding LaAlO ₃ /SrTiO ₃ Micro-membranes
PA-36	Laszlo Cline (Northwestern Univ.)	Local Strain Engineering of Freestanding Crystalline SrTiO ₃ Membranes
PA-37	Sayaka Shindo (The Univ. of Osaka)	Structural phase transformation freestanding zirconia membranes
PA-38	José Martín Martínez Botana (Universidad Santiago de Compostela)	Solid-state electrochemical functionalization of YBCO free-standing membranes
PA-39	Rahil Haria (Imperial College London)	Polar Textures from Ferroelastic Topology in a Metal Membrane
PA-40	Evgenios Stylianidis (TU Wien)	Guidelines for sputtering growth of strontium aluminate and ferromagnetic Sm ₂ NiMnO ₆ membranes
PA-41	Hiroaki Nishikawa (Kindai Univ.)	Transfer of ZnO Thin Films Enabled by a Two-Step Sacrificial Layer Approach for Functional Hexagonal Crystal Films
PA-42	Yuzuki Uchida (Tohoku Univ.)	Highly Conductive Single-Crystalline Nb-Doped TiO ₂ Membranes and Photochemically Accelerated Lift-Off for Transparent Oxides
PA-43	Keitaro Kanno (Science Tokyo)	van der Waals epitaxy of Ti ₂ O ₃ films on hexagonal boron nitride toward freestanding oxide membranes
PA-44	Nicole Engel (TU Darmstadt)	Transfer Approaches for Free-Standing Perovskite Oxide Membranes
PA-45	Seung Hyup Lee (Seoul National Univ.)	Internal Bias Relaxation and Defect-Mediated Polarization Instability in Ferroelectric Al _{0.72} Sc _{0.28} N Thin Films
PA-46	Jungwoo Cho (Seoul National Univ.)	Boosting Inversion Symmetry Breaking in Epitaxial Tetragonal ZrO ₂ via Atomic Layer Deposition
PA-47	Honghyun Jeon (Sungkyunkwan Univ.)	Tunable ferroelectricity in epitaxial HfO ₂ /ZrO ₂ multilayers via interface engineering
PA-48	Minche Jo (Pusan National Univ.)	First-Principles EELS spectrum analysis in defective HfO ₂
PA-49	Sizhao Huang (Technical Univ. of Denmark)	Electro-Chemo-Mechanical Coupling in Hf _{0.5} Zr _{0.5} O ₂ Ferroionic Heterostructures
PA-50	Anudeep Tullibilli (IISc Bengaluru)	Correlating Surface Topography with Ferroelectric and Leakage Phenomena in Hafnia Thin Films

PA-51	Jinkyu Han (Jeonbuk National Univ.)	Phase Transition Temperature Evolution in Ferroelectric Nanotubes with Different Wall Thicknesses via Electrical and Structural Characterization
PA-52	Roham Talei Jeid (Univ. of Stuttgart)	Substrate-Controlled Ferroelectric Domain Structure in Epitaxial BaTiO ₃ : A Real-Space View of the Oxygen Octahedral Network
PA-53	Yuhan Liang (Tsinghua Univ.)	Unconventional magnon spin polarization enabled by ferroelectric domain engineering in multiferroic oxide
PA-54	Sunu Park (Jeonbuk National Univ.)	Effect of PbTiO ₃ Nanotube Wall Thickness on Piezoelectric Nanogenerator Performance
PA-55	Jiyong Hyun (Jeonbuk National Univ.)	Hydrothermal Synthesis of Tetragonal BaTiO ₃ Nanotubes for Efficient Piezoelectric Nanogenerators
PA-56	Geri Topore (Imperial College London)	Atomic-scale characterisation of multiferroic oxide Aurivillius thin films using Transmission Electron Microscopy and Atom Probe Tomography
PA-57	Lee Koomok (Science Tokyo)	Electric-Field-induced Weakly Ferromagnetic Domain Change by Ferroelectric Topological Domain Switching in Co-Substituted BiFeO ₃ Nanodots
PA-58	Tomohiro Yabuki (Tokyo Univ. of Science)	RF-magnetron-Sputtered Sc:TiO ₂ Thin Films Exhibiting High-ON/OFF ratio Bipolar Resistive Switching Properties
PA-59	Tom Zander (Univ. of Cologne)	Antiferroelectric-like polarization reversal induced by ordered polar vortices
PA-60	Masao Nakamura (Tohoku Univ.)	Giant shift current in ferroelectric halide perovskite CsGeI ₃ epitaxial thin films
PA-61	Chihwan An (Seoul National Univ.)	Expanding the Polarization Window of Epitaxial Hf _x Zr _{1-x} O ₂ through an Unconventional Ferroelectric Switching Pathway
PA-62	Janine Gückelhorn (Institut de Ciència de Materials de Barcelona)	Enhanced Rashba Spin-Orbit Interactions in polar oxide 2DEGs
PA-63	Thomas Buttiens (Laboratoire Albert Fert)	Toward Non-Volatile Ferroelectric Spin-Orbit Devices: A Room-Temperature 2DEG in STO/PZT Heterostructures
PA-64	Yeonjae Lee (Seoul National Univ.)	Interfacial polarity control of anomalous Hall effect in LaCoO ₃ -SrIrO ₃ heterostructures
PA-65	Tatsuro Endo (The Univ. of Tokyo)	Room-temperature spin-polarized transport in SrTiO ₃ -based two-dimensional electron gas
PA-66	Chun-chung Hsu (National Tsing Hua Univ.)	Configurational-Entropy-Enabled Tunable Relaxor Transition and Dielectric Response Broadening in High-Entropy Ferroelectric Thin Films
PA-67	Si Won Kim	Potential realization of geometrical ferroelectricity in iron-based

PA-68	Akiko Kamigaito (Ochanomizu Univ.)	Ferroelectricity and magnetic order at room temperature and electronic states of bismuth iron oxyfluoride thin films
PA-69	Yuuki Masutake (Tohoku Univ.)	Engineering Interfacial Charge Transfer in SrNbO ₃ /SrTiO ₃ heterostructures via SrZrO ₃ barrier layers toward the development of transparent oxide transistors
PA-70	Hyeonjun Kong (Hokkaido Univ.)	Flexible In ₂ O ₃ Thin-Film Transistors with High-Mobility (~75 cm ² V ⁻¹ s ⁻¹)
PA-71	Tohru Higuchi (Tokyo Univ. of Science)	All-Solid-State Redox Transistor Using VO ₂ Thin Film and Li ⁺ Solid Electrolyte
PA-72	Ertürk Enver Yildirim (TU Dresden)	Solution-Processed All-Metal-Oxide Permeable-Base Transistors for High-Current-Density Vertical Oxide Electronics
PA-73	Hisashi Inoue (AIST)	Human-Interactive Reservoir Computing using an Oxide Ionic Drift-Diffusion Transistor
PA-74	Muhaimin Mareum Khan (Cornell Univ.)	First Demonstration of Suboxide Molecular-beam epitaxy Grown p-Type SnO TFT
PA-75	Satoshi Hamasuna (Kyushu Univ.)	Harnessing Surface-Dominant Proton Transport for Reservoir Computing in VO ₂ Two-Terminal Devices
PA-76	Harutaka Koyama (Waseda Univ.)	Low-Temperature RF Switching Device Using the Metal-Insulator Transition of W-Doped VO ₂ Thin Films
PA-77	Max Buczek (Forschungszentrum Jülich)	Amorphous, Highly Conductive Pr _{0.7} Ca _{0.3} MnO ₃ for Area-Dependent Resistive Switching Devices
PA-78	Maya Umezaki (The Univ. of Osaka)	Observation of Resistive Switching in NbO ₂ Thin Films and Analysis Using a Two-State Model
PA-79	Ever Quintero-camargo (Univ. of Twente)	Tailoring a Novel Li _{1.25} Cr _{0.25} Ti _{1.5} O ₄ Anode for Thin Film Microbatteries
PA-80	Kazunori Nishio (The Univ. of Tokyo)	Interfacial Engineering for Rapid Charging 5V-Class Thin-Film All-Solid-State Li Batteries
PA-81	Kota Hanzawa (Science Tokyo)	A Novel Transparent n-Type Semiconductor β-TeO ₃
PA-82	Ryota Takahashi (Nihon Univ.)	PLD Growth of ZnO/Mg _x Zn _{1-x} O Superlattices for Quantum Cascade Laser
PA-83	Ojas Shanker (Univ. of Twente)	Calcium Niobate Nanosheet templated monolithic integration of Barium Titanate thin films for Silicon Nitride Integrated Photonics
PA-84	Takanori Shinohara (Tokyo Metropolitan Univ.)	Epitaxial Synthesis and Physical Properties of BaNbO ₃ as a Transparent Conductor

